

# 2MBI800U4G-120

**IGBT Modules** 

# **IGBT MODULE (U series)** 1200V / 800A / 2 in one package

#### Features

High speed switching Voltage drive Low Inductance module structure

#### Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines



### Maximum Ratings and Characteristics

■ Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units	
Collector-Emitter voltage		Vces			1200	V	
Gate-Emitter voltage		V <sub>GES</sub>			±20	V	
Collector current		Ic	Continuous	Tc=25°C	1200		
			Continuous	Tc=80°C	800		
		Ic pulse	1ms	Tc=25°C	2400	۸	
				Tc=80°C	1600	Α	
		-lc			800		
		-lc pulse	1ms	1ms			
Collector power dissipation		Pc	1 device	1 device		W	
Junction temperature		Tj			150	°C	
Storage temperature		Tstg			-40 ~ +125		
Isolation voltage	lation voltage Between terminal and copper base (*1)		AC : 1min.		4000	VAC	
Screw torque	Mounting (*2)	M6			5.75		
	Terminals (*3)	M8			10	N m	
		M4			2.5		

Note \*1: All terminals should be connected together when isolation test will be done.

Note \*2: Recommendable Value: Mounting 4.25~5.75 Nm (M6)

Note \*3: Recommendable Value: Main Terminals 8~10 Nm (M8)

Sense Terminals 1.7~2.5 Nm (M4)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

Itama	Cumbala	Conditions		Characteristics			11!4	
Items	Symbols			min.	typ.	max.	Units	
Zero gate voltage collector current	Ices	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 1200V		-	-	1.0	mA	
Gate-Emitter leakage current $I_{GES}$ $V_{CE} = 0V, V_{GE} = \pm 20$		$V_{CE} = 0V$ , $V_{GE} = \pm 20V$	20V		-	1600	nA	
Gate-Emitter threshold voltage	Emitter threshold voltage   VGE (th)   VCE = 20V, Ic = 800mA			5.5	6.5	7.5	V	
	V <sub>CE (sat)</sub>		Tj=25°C	-	2.12	2.29	V	
Collector Emitter acturation valtage	(main terminal)	V <sub>GE</sub> = 15V	Tj=125°C	-	2.32	-		
Collector-Emitter saturation voltage	V <sub>CE (sat)</sub>	Ic = 800A	Tj=25°C	-	1.90	2.05		
	(chip)		Tj=125°C	-	2.10	-		
Input capacitance	Cies	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0V, f = 1MHz		-	90	-	nF	
Turn-on	ton	$V_{cc} = 600V$ $R_{con} = 5.6\Omega$ $R_{coff} = 1.5\Omega$		-	1.35	-		
turn-on	tr			-	0.65	-		
T	toff	V <sub>GE</sub> = ±15V		-	0.80	-	μs	
Turn-off	tf	Tj = 125°C		-	0.20	-	٦	
	VF		Tj=25°C	-	1.87	2.04		
Famurand on violence	(main terminal)	$V_{GE} = 0V$	Tj=125°C	-	1.97	-	V	
Forward on voltage	V <sub>F</sub>	I⊧ = 800A	Tj=25°C	-	1.65	1.80		
	(chip)		Tj=125°C	-	1.75	-		
Reverse recovery	trr	I <sub>F</sub> = 800A	-	-	0.45	-	μs	
Lead resistance, terminal-chip	R lead			-	0.27	_	mΩ	

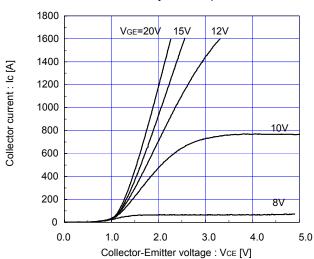
#### Thermal resistance characteristics

- 11011111111110101111110101101101									
Items	Symbols	Conditions	Characteristics			Units			
items	Syllibols	Conditions	min.	typ.	max.	Ullits			
Thermal registeres (1device)	Rth(j-c)	IGBT	-	-	0.026	°C/W			
Thermal resistance (1device)		FWD	-	-	0.045				
Contact thermal resistance (1device)	Rth(c-f)	with Thermal Compound (*4)	_	0.006	-				

Note \*4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

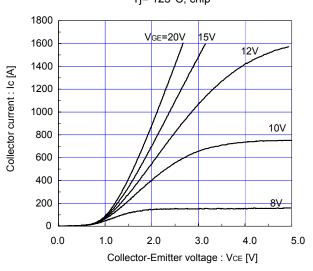
#### ■ Characteristics (Representative)

Collector current vs. Collector-Emitter voltage (typ.) Tj=25°C,chip

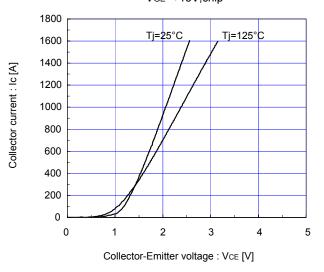


Collector current vs. Collector-Emitter voltage (typ.)

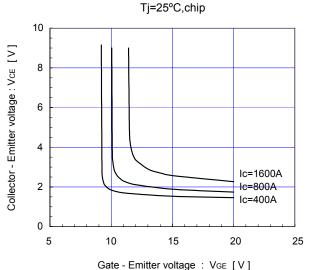
Tj= 125°C, chip



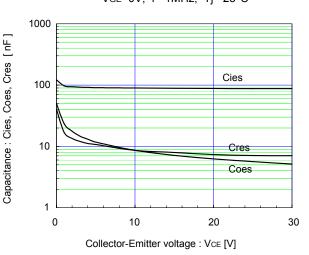
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) V<sub>GE</sub>=+15V,chip



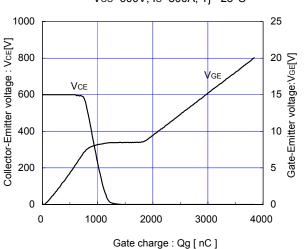
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.)



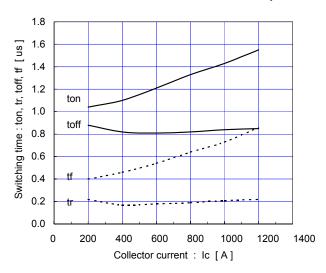
Capacitance vs. Collector-Emitter voltage (typ.) VGE=0V, f= 1MHz, Tj= 25°C



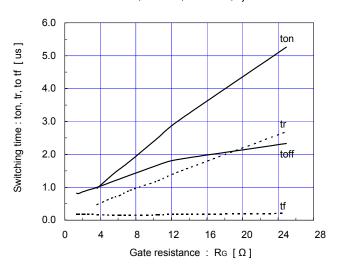
Dynamic Gate charge (typ.) Vcc=600V, Ic=800A, Tj= 25°C



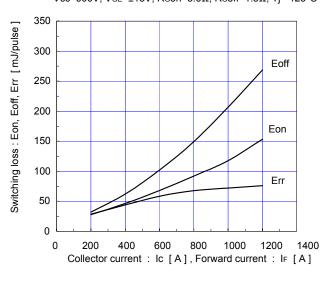
Switching time vs. Collector current (typ.) Vcc=600V, VgE= $\pm$ 15V, Rgon= $5.6\Omega$ , Rgoff= $1.5\Omega$ , Tj=  $125^{\circ}$ C



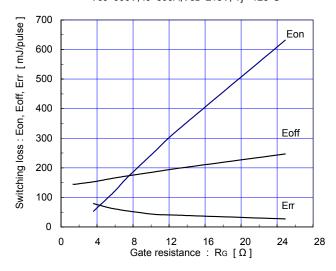
Switching time vs. Gate resistance (typ.) Vcc=600V, Ic=800A,VGE=±15V, Tj= 125°C



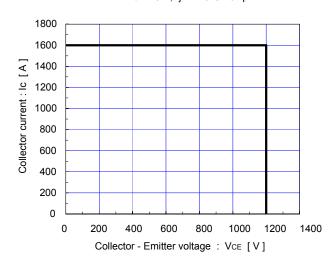
Switching loss vs. Collector current (typ.) Vcc=600V, VgE= $\pm$ 15V, Rgon= $5.6\Omega$ , Rgoff= $1.5\Omega$ , Tj=  $125^{\circ}$ C



Switching loss vs. Gate resistance (typ.) Vcc=600V, Ic=800A,VgE=±15V, Tj= 125°C

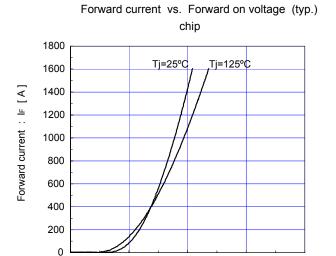


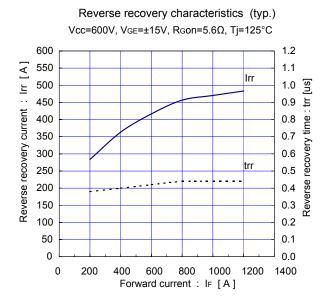
Reverse bias safe operating area (max.) ± V<sub>GE</sub>=15V ,Tj = 125°C / chip



0.0

1.0





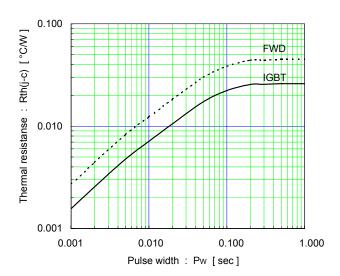
Transient thermal resistance (max.)

2.0

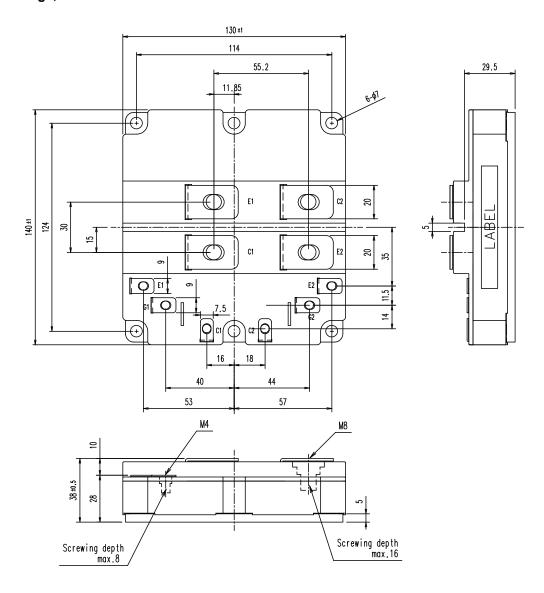
Forward on voltage  $: V_F [V]$ 

3.0

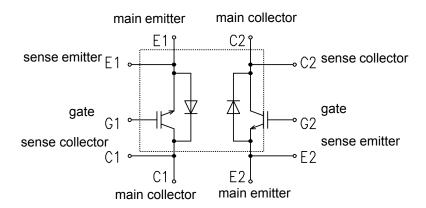
4.0



# ■ Outline Drawings, mm



# **■** Equivalent Circuit Schematic



http://www.fujielectric.com/products/semiconductor/

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- · Machine tools
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